NSN 5962-01-143-6833

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View Online at https://aerobasegroup.com/nsn/5962-01-143-6833

Body Length:

Between 1.235 inches and 1.285 inches

Body Width:

Between 0.515 inches and 0.600 inches

Body Height:

Between 0.145 inches and 0.175 inches

Maximum Power Dissipation Rating:

525.0 milliwatts

Operating Tempurature Range:

-10.0/+80.0 degrees celsius

Storage Tempurature Range:

-65.0/+125.0 degrees celsius

End Application:

Bit verificat 82577

Features Provided:

Erasable and programmable and static operation and high speed

Inclosure Material:

Ceramic

Inclosure Configuration:

Dual-in-line

Output Logic Form:

Transistor-transistor logic

Input Circuit Pattern:

11 input

Terminal Surface Treatment:

Solder

Voltage Rating And Type Per Characteristic:

6.0 volts power source

Time Rating Per Chacteristic:

650.00 nanoseconds propagation delay time, low to high level output

Memory Device Type:

Rom

Test Data Document:

82577-1090135 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing)

Terminal Type And Quantity:

24 printed circuit

Shelf Life:

N/a

Unit Of Measure:

Demilitarization:

Yes - demil/mli

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